NSB1706DMW5T1G

Dual Bias Resistor Transistor

NPN Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. These digital transistors are designed to replace a single device and its external resistor bias network. The BRT eliminates these individual components by integrating them into a single device. In the NSB1706DMW5T1G, two BRT devices are housed in the SC-88A package which is ideal for low power surface mount applications where board space is at a premium.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

(T_A = 25°C unless otherwise noted, common for Q₁ and Q₂)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	Vdc
Collector-Emitter Voltage	V _{CEO}	50	Vdc
Collector Current	lc	100	mAdc

THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit	
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D	187 (Note 1) 256 (Note 2) 1.5 (Note 1) 2.0 (Note 2)	mW mW/°C	
Thermal Resistance, Junction-to-Ambient	R _{θJA} 670 (Note 1 490 (Note 2		°C/W	
Characteristic (Both Junctions Heated)	Symbol	Max	Unit	
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D	250 (Note 1) 385 (Note 2) 2.0 (Note 1) 3.0 (Note 2)	mW mW/°C	
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	493 (Note 1) 325 (Note 2)	°C/W	
Thermal Resistance, Junction-to-Lead	$R_{ heta JL}$	188 (Note 1) 208 (Note 2)	°C/W	
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C	

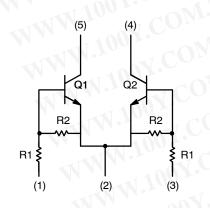
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

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SC-88A CASE 419A STYLE 1

MARKING DIAGRAM



U6 = Device Marking
M = Date Code
= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]	< ·
NSB1706DMW5T1G	SC-88A (Pb-Free)	3000 / Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

^{1.} FR-4 @ Minimum Pad.

^{2.} FR-4 @ 1.0 x 1.0 inch Pad.

NSB1706DMW5T1G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, common for Q₁ and Q₂)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		No.	Co	- 17	N
Collector-Base Cutoff Current (V _{CB} = 50 V, I _E = 0)	I _{CBO}	100	CO	100	nAdc
Collector-Emitter Cutoff Current (V _{CE} = 50 V, I _B = 0)	I _{CEO}	Tāo	v.C	500	nAdc
Emitter-Base Cutoff Current $(V_{EB} = 6.0 \text{ V, } I_{C} = 0)$	I _{EBO}	1.70	~ .C	0.18	mAdo
Collector-Base Breakdown Voltage ($I_C = 10 \mu A, I_E = 0$)	V _{(BR)CBO}	50		$CQ_{\overline{D}}$	Vdc
Collector-Emitter Breakdown Voltage (Note 3) (I _C = 2.0 mA, I _B = 0)	V _{(BR)CEO}	50	105	7.CO	Vdc
ON CHARACTERISTICS (Note 3)		-133	100		M
DC Current Gain (V _{CE} = 10 V, I _C = 5.0 mA)	h _{FE}	80	200	1	
Collector-Emitter Saturation Voltage (I _C = 10 mA, I _B = 1 mA)	V _{CE(sat)}	NAN	- N 1	0.25	Vdc
Output Voltage (on) $(V_{CC} = 5.0 \text{ V}, V_B = 2.5 \text{ V}, R_L = 1.0 \text{ k}\Omega)$	V _{OL}	11/1	- - 1	0.2	Vdc
Output Voltage (off) (V_{CC} = 5.0 V, V_{B} = 0.25 V, R_{L} = 1.0 k Ω)	V _{OH}	4.9	N 2	100	Vdc
Input Resistor	R1	3.3	4.7	6.1	kΩ
			Ì	21 NN	U.

R1/R2

0.055

0.185

NOTE: New resistor combinations. Updated curves to follow in subsequent data sheets.

Resistor Ratio

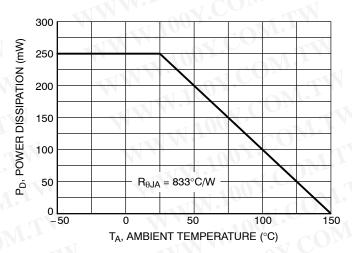


Figure 1. Derating Curve

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^{3.} Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%.

NSB1706DMW5T1G

PACKAGE DIMENSIONS

SC-88A, SOT-353, SC-70 CASE 419A-02 **ISSUE J**

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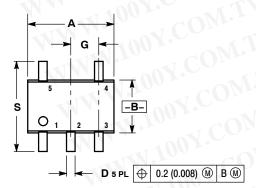
NOTES:

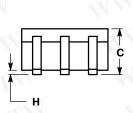
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH. 419A-01 OBSOLETE. NEW STANDARD
- 3. 419A-02
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

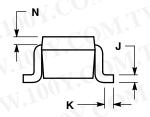
	INCHES		MILLIM	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026 BSC 0.004		0.65 BSC		
н				0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N 🔻	0.008	REF	0.20 REF		
S	0.079	0.087	2.00	2.20	

- STYLE 1: PIN 1. BASE
 - 2. EMITTER 3. BASE

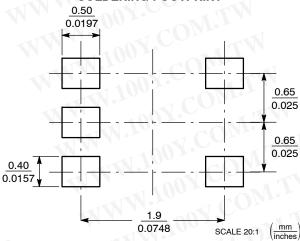
 - COLLECTOR COLLECTOR







SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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